

# DB101S THRU DB107S

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## DB101S THRU DB107S

1.0A Miniature Glass Passivated  
Single-Phase Surface Mount  
Bridge Rectifiers-50-1000V

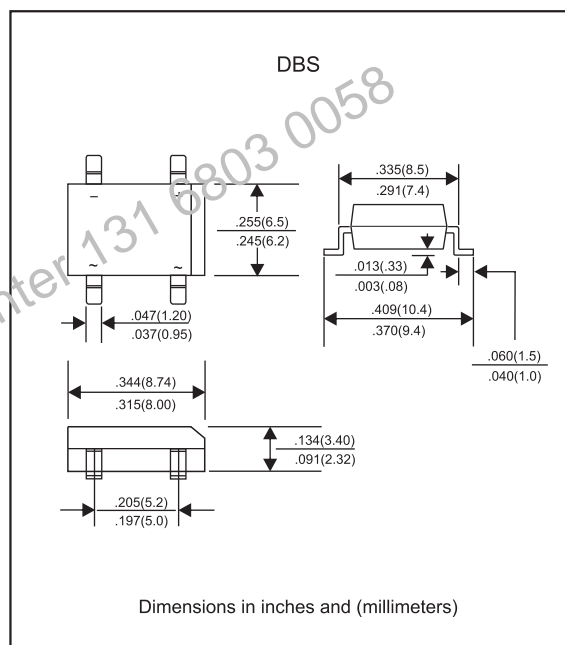
## Features

- Surge overload ratings to 30 amperes peak.
- Save space on printed circuit board.
- Ideal for automated replacement.
- Reliable low cost construction utilizing molded plastic technology results in inexpensive product.
- Glass passivated chip junctions.
- Lead-free parts meet RoHS requirements.
- UL recognized file # E321971
- Suffix "-H" indicates Halogen free parts, ex. DB101S-H.

## Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, DBS
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : marked on body
- Mounting Position : Any
- Weight : Approximated 0.38 gram

## Package outline

Maximum ratings and Electrical Characteristics (AT  $T_A=25^\circ\text{C}$  unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	See Fig.1	$I_o$			1.0	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC methode)	$I_{FSM}$			50	A
Reverse current	$V_R = V_{RRM} \quad T_J = 25^\circ\text{C}$	$I_R$			10	uA
	$V_R = V_{RRM} \quad T_J = 125^\circ\text{C}$				500	
Diode junction capacitance	f=1MHz and applied 4V DC reverse voltage	$C_J$		25		pF
Storage temperature		$T_{STG}$	-65		+175	$^\circ\text{C}$

SYMBOLS	$V_{RRM}^{*1}$ (V)	$V_{RMS}^{*2}$ (V)	$V_R^{*3}$ (V)	$V_F^{*4}$ (V)	Operating temperature $T_J, (^\circ\text{C})$
DB101S	50	35	50	1.10	-55 to +150
DB102S	100	70	100		
DB103S	200	140	200		
DB104S	400	280	400		
DB105S	600	420	600		
DB106S	800	560	800		
DB107S	1000	700	1000		

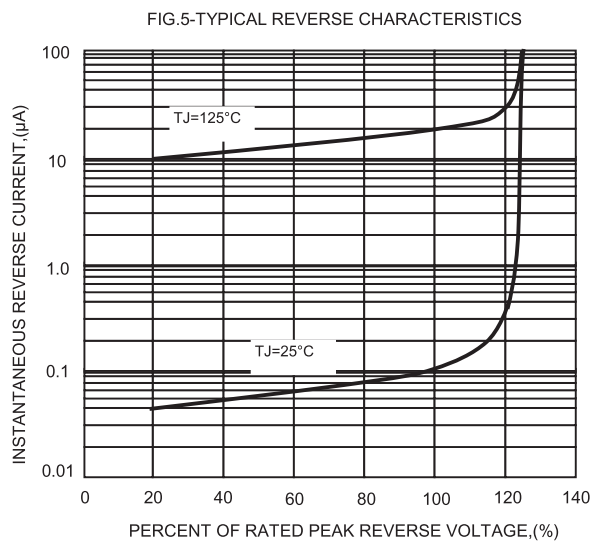
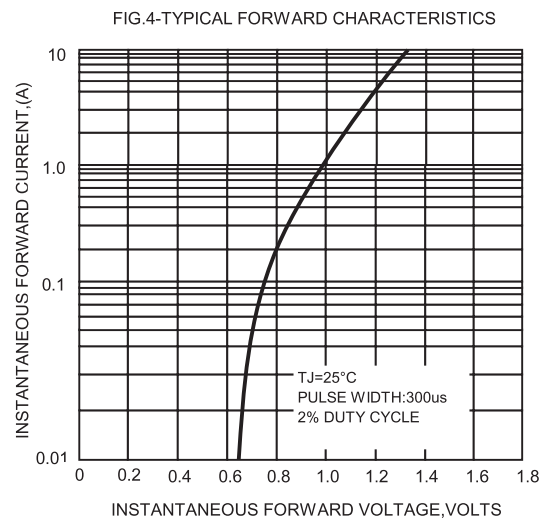
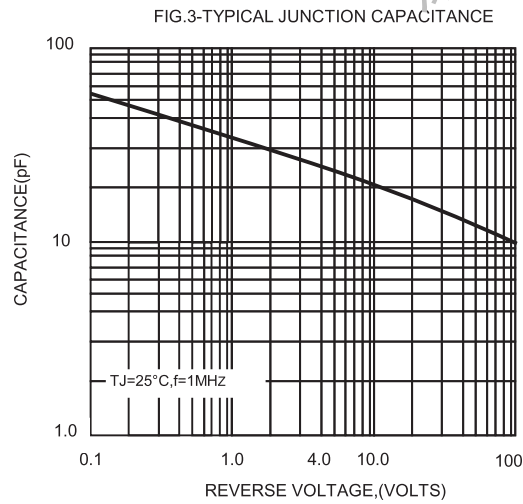
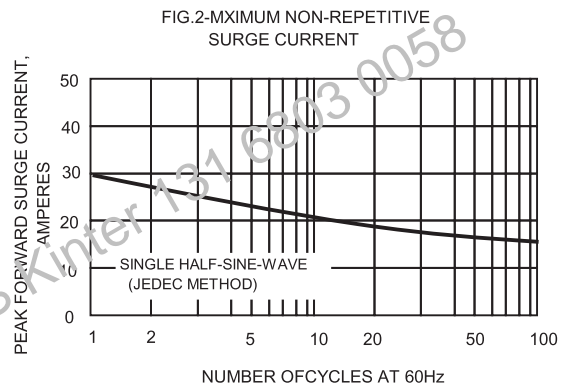
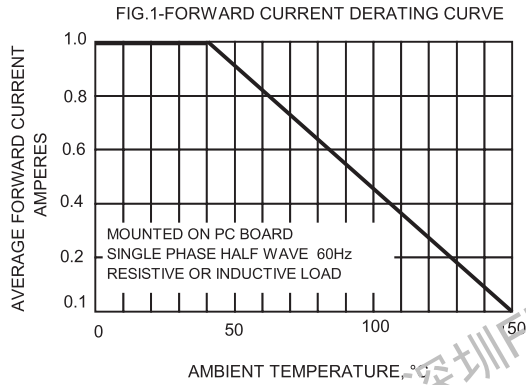
\*1 Repetitive peak reverse voltage

\*2 RMS voltage

\*3 Continuous reverse voltage

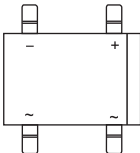
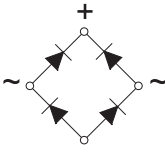
\*4 Maximum forward voltage @  $I_F=1.0A$

## Rating and characteristic curves (DB101S THRU DB107S)



## DB101S THRU DB107S

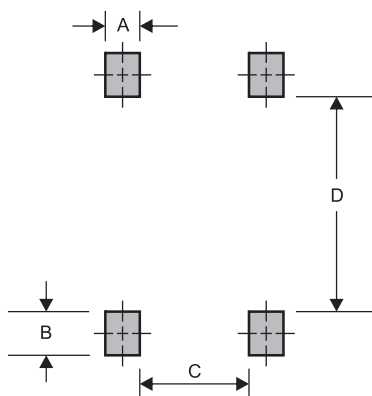
## Pinning information

Simplified outline	Symbol
	

## Marking

Type number	Marking code
DB101S	DB101S
DB102S	DB102S
DB103S	DB103S
DB104S	DB104S
DB105S	DB105S
DB106S	DB106S
DB107S	DB107S

## Suggested solder pad layout

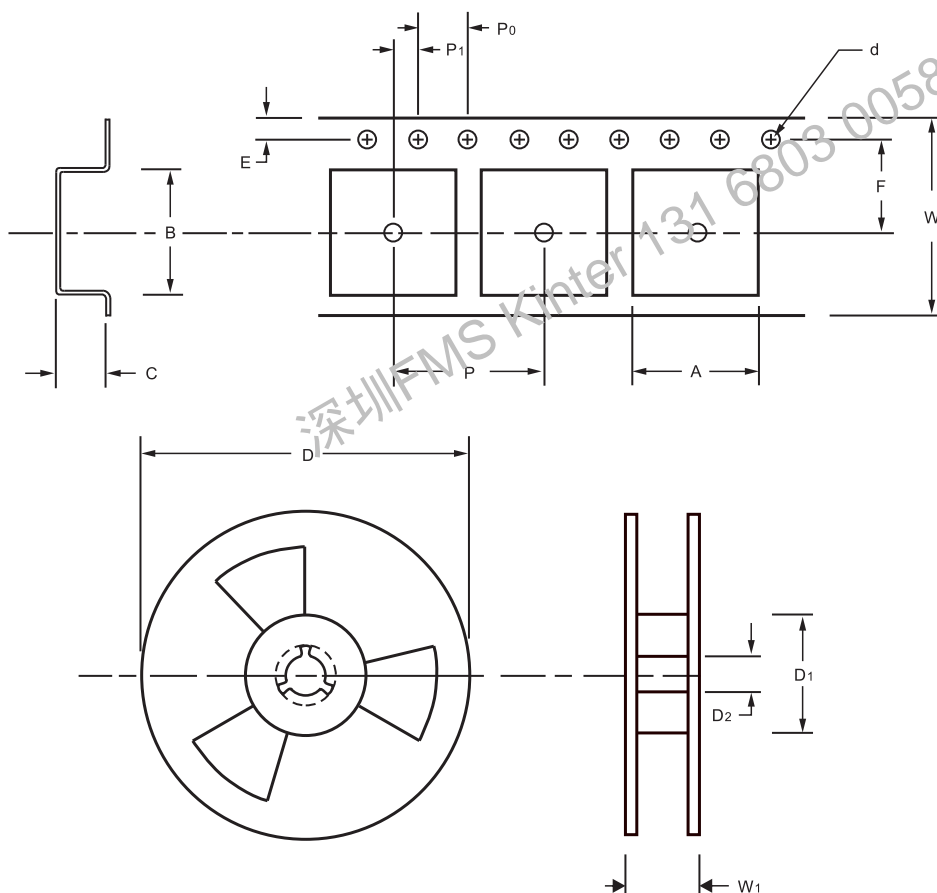


Dimensions in inches and (millimeters)

PACKAGE	A	B	C	D
DBS	0.059 (1.50)	0.047 (1.20)	0.157 (4.00)	0.291 (7.40)

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## Packing information



unit:mm

Item	Symbol	Tolerance	DBS
Carrier width	A	0.1	8.64
Carrier length	B	0.1	10.41
Carrier depth	C	0.1	3.50
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	330.00
13" Reel inner diameter	D1	min	50.00
7" Reel outside diameter	D	2.0	-
7" Reel inner diameter	D1	min	-
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	7.50
Punch hole pitch	P	0.1	12.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.30
Tape width	W	0.3	16.00
Reel width	W1	1.0	22.00

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

## DB101S THRU DB107S

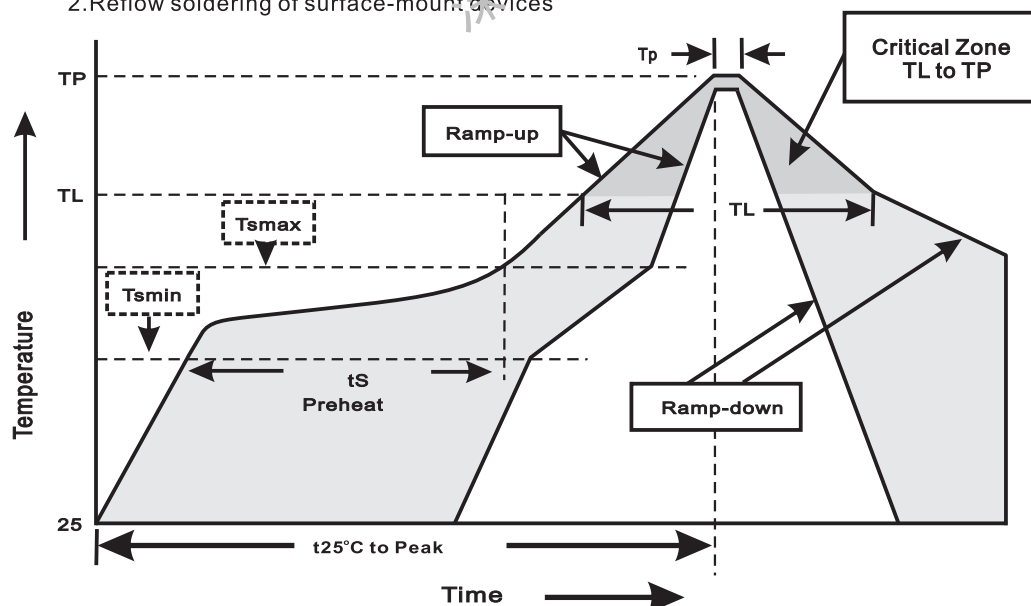
## Reel packing and tube packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
DBS	13"	1000	12.0	2000	337*337*37	330	350*330*360	12,000	12.0

PACKAGE	TUBE (pcs)	TUBE SIZE (m/m)	BOX (pcs)	INNER BOX (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
DBS	50	452*13.9*5.8	5000	450*145*73	470*240*310	30,000	21.0

## Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



## 3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate( $T_L$ to $T_P$ )	<3°C/sec
Preheat -Temperature Min( $T_{smin}$ ) -Temperature Max( $T_{smax}$ ) -Time(min to max)( $t_s$ )	150°C 200°C 60~120sec
$T_{smax}$ to $T_L$ -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature( $T_L$ ) -Time( $t_L$ )	217°C 60~260sec
Peak Temperature( $T_P$ )	255°C-0/+5°C
Time within 5°C of actual Peak Temperature( $t_P$ )	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes

## DB101S THRU DB107S

## High reliability test capabilities

Item Test	Conditions	Reference
1. Solder Resistance	at $260 \pm 5^\circ\text{C}$ for $10 \pm 2$ sec. immerse body into solder $1/16" \pm 1/32"$	MIL-STD-750D METHOD-2031
2. Solderability	at $245 \pm 5^\circ\text{C}$ for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	$V_R = 80\%$ rate at $T_J = 150^\circ\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
4. Forward Operation Life	Rated average rectifier current at $T_A = 25^\circ\text{C}$ for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	$T_A = 25^\circ\text{C}$ , $I_F = I_O$ On state: power on for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	$15P_{SIG}$ at $T_A = 121^\circ\text{C}$ for 4 hrs.	JESD22-A102
7. Temperature Cycling	$-55^\circ\text{C}$ to $+125^\circ\text{C}$ dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Thermal Shock	$0^\circ\text{C}$ for 5 min. rise to $100^\circ\text{C}$ for 5 min. total 10 cycles.	MIL-STD-750D METHOD-1056
9. Forward Surge	8.3ms single half sine-wave superimposed on rated load, one surge.	MIL-STD-750D METHOD-4066-2
10. Humidity	at $T_A = 85^\circ\text{C}$ , RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
11. High Temperature Storage Life	at $175^\circ\text{C}$ for 1000 hrs.	MIL-STD-750D METHOD-1031